

MICROCIRCUIT DATA SHEET

Original Creation Date: 07/19/95 Last Update Date: 03/28/02 Last Major Revision Date: 03/16/00

QUAD OPERATIONAL AMPLIFIER, SINGLE SUPPLY, LOW POWER

General Description

MJLM124-X REV 1B1

The LM124 consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits which now can be more easily implemented in single power supply systems. For example, the LM124 can be directly operated off of the standard +5 VDC power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional +15 VDC power supplies.

Industry Part Number

NS Part Numbers

LM124

JL124BCA JL124BDA JL124BZA JL124SCA JL124SDA

Prime Die

LM124

Controlling Document

38510/11005,AMEND.2 CIR.F REV B

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp	(°C)
1	Static tests at	+25	

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2	2	Static tests at	+125
3	3	Static tests at	-55
4	4	Dynamic tests at	+25
5	5	Dynamic tests at	+125
6	5	Dynamic tests at	-55
7	7	Functional tests at	+25
8	3A	Functional tests at	+125
8	3B	Functional tests at	-55
9	9	Switching tests at	+25
1	10	Switching tests at	+125
1	11	Switching tests at	-55

(Absolute Maximum Ratings)

(Note 1)

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Power Dissipation
    CERDIP
                                                            400mW
    CERPACK
                                                            350mW
    CERAMIC SOIC
                                                           350mW
Supply Voltage
                                                           36Vdc or \pm 18Vdc
Input Voltage Differential
                                                           30Vdc
Input Voltage
                                                           -0.03Vdc to +32Vdc
Input Current
 (Note 3)
    (Vin < -0.3 Vdc)
                                                           10 to 0.1mA
Output Short-Circuit to GND
 (Note 4)
    (One Amplifier)
    V+ \leq 15Vdc and TA = 25 C
                                                           Continuous
Operating Temperature Range
                                                           -55 C \leq Ta \leq +125 C
Maximum Junction Temperature
 (Note 2)
                                                           175 C
Storage Temperature Range
                                                           -65 C \leq Ta \leq +150 C
Lead Temperature
    (Soldering, 10 seconds)
                                                           260 C
Thermal Resistance
    ThetaJA
    CERDIP
                   (Still Air)
                                                           120 C/W
                   (500LF/Min Air Flow)
                                                            51 C/W
                   (Still Air)
                                                           140 C/W
    CERPACK
                   (500LF/Min Air Flow)
                                                           116 C/W
                  (Still Air)
    CERAMIC SOIC
                                                           140 C/W
                   (500LF/Min Air Flow)
                                                           116 C/W
    ThetaJC
    CERDIP
                                                            35 C/W
    CERPACK
                                                            60 C/W
                                                            60 C/W
    CERAMIC SOIC
Package Weight
    CERDIP
                                                           TBD
    CERPACK
                                                            460mg
    CERAMIC SOIC
                                                           410mg
ESD Tolerance
 (Note 5)
                                                           250 V
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- Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- when the device is not operated under the listed test conditions.

 Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is Pdmax = (Tjmax TA) /ThetaJA or the number given in the Absolute Maximum Ratings, whichever is lower.

(Continued)

- Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 VDC (at 25 C).
- Note 4: Short circuits from the output to V+ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 40 mA independent of the magnitude of V+. At values of supply voltage in excess of +15 VDC, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.
- Note 5: Human body model, 1.5K ohms in series with 100 pF.

DC PARAMETERS

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Vio	Input Offset Voltage	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-5	5	mV	1
					-7	7	mV	2, 3
		Vcc+ = 2V, Vcc- = -28V, Vcm = 13V			-5	5	mV	1
					-7	7	mV	2, 3
		Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V			-5	5	mV	1
					-7	7	mV	2, 3
		Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V			-5	5	mV	1
					-7	7	mV	2, 3
Iio	Input Offset Current	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-30	30	nA	1, 2
	Current				-75	75	nA	3
		Vcc+ = 2V, Vcc- = -28V, Vcm = 13V			-30	30	nA	1, 2
					-75	75	nA	3
		Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V			-30	30	nA	1, 2
					-75	75	nA	3
		Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V			-30	30	nA	1, 2
					-75	75	nA	3
+Iib	Input Bias	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-150	+0.1	nA	1, 2
	Current				-300	+0.1	nA	3
		Vcc+ = 2V, Vcc- = -28V, Vcm = 13V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
		Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
		Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3

DC PARAMETERS (Continued)

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
-Iib	Input Bias Current	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
		Vcc+ = 2V, Vcc- = -28V, Vcm = 13V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
		Vcc+ = 5V, Vcc- = Gnd, Vcm = -1.4V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
		Vcc+ = 2.5V, Vcc- = -2.5V, Vcm = 1.1V			-150	+0.1	nA	1, 2
					-300	+0.1	nA	3
+PSRR	Power Supply Rejection Ratio	$Vcc- = Gnd$, $Vcm = -1.4V$, $5V \le Vcc \le 30V$			-100	100	uV/V	1, 2,
CMRR	Common Mode Rejection Ratio				76		dB	1, 2,
Ios+	Output Short Circuit Current	Vcc+ = 30V, Vcc - = Gnd, Vo = +25V			-70		mA	1, 2,
Icc	Power Supply Current	Vcc+ = 30V, Vcc - = Gnd				3	mA	1, 2
	Current					4	mA	3
Delta Vio/Delta T	Input Offset Voltage Temperature	$+25 \text{ C} \leq \text{TA} \leq +125 \text{ C}, +\text{Vcc} = 5\text{V}, \\ -\text{Vcc} = 0\text{V}, \text{Vcm} = -1.4\text{V}$	3		-30	30	uV/ (2 2
1	Sensitivity	$-55 \text{ C} \le \text{TA} \le +25 \text{ C}, +\text{Vcc} = 5\text{V}, \\ -\text{Vcc} = 0\text{V}, \text{Vcm} = -1.4\text{V}$	3		-30	30	uV/ (2 3
Delta Iio/Delta T	Input Offset Current Temperature	$+25 \text{ C} \leq \text{TA} \leq +125 \text{ C}, +\text{Vcc} = 5\text{V}, \\ -\text{Vcc} = 0\text{V}, \text{Vcm} = -1.4\text{V}$	3		-400	400	pA/ (2 2
1	Sensitivity	$-55 \text{ C} \le \text{TA} \le +25 \text{ C}, +\text{Vcc} = 5\text{V}, \\ -\text{Vcc} = 0\text{V}, \text{Vcm} = -1.4\text{V}$	3		-700	700	pA/ (2 3
Vol	Logical "0" Output Voltage	Vcc+ = 30V, Vcc- = Gnd, Rl = 10K Ohms				35	mV	4, 5, 6
		Vcc+ = 30V, Vcc- = Gnd, Iol = 5mA				1.5	V	4, 5, 6
		Vcc+ = 4.5V, Vcc- = Gnd, Iol = 2uA				0.4	V	4, 5,
Voh	Logical "1" Output Voltage	Vcc+ = 30V, Vcc- = Gnd, Ioh = -10mA			27		V	4, 5,
		Vcc+ = 4.5V, Vcc- = Gnd, Ioh = -10mA			2.4		V	4, 5
					2.3		V	6

DC PARAMETERS (Continued)

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Avs+	Voltage Gain	Vcc+ = 30V, Vcc- = Gnd, 1V < Vo < 26V, R1 = 10K Ohms	1		50		V/mV	4
			1		25		V/mV	5, 6
		Vcc+ = 30V, Vcc- = Gnd, 5V < Vo < 20V, R1 = 2K Ohms	1		50		V/mV	4
			1		25		V/mV	5, 6
Avs	Voltage Gain	$Vcc+ = 5V$, $Vcc- = Gnd$, $1V \le Vo \le 2.5V$, $Rl = 10K$ Ohms	1		10		V/mV	4, 5, 6
		$ \begin{array}{llllllllllllllllllllllllllllllllllll$	1		10		V/mV	4, 5, 6
+Vop	Maximum Output Voltage Swing	Vcc+ = 30V, Vcc- = Gnd, Vo = +30V, R1 = 10K Ohms			27		V	4, 5, 6
		Vcc+ = 30V, Vcc- = Gnd, Vo = +30V, R1 = 2K Ohms			26		V	4, 5, 6
Vio(a)	Tempco Screen		4			2.3	mV	
Vio(b)	Tempco Screen		4			2.5	mV	
Iio(a)	Tempco Screen		4			20	nA	
Iio(b)	Tempco Screen		4			16	nA	
+Iib(a)	Tempco Screen		4			16	nA	
+Iib(b)	Tempco Screen		4			10	nA	
+Iib(c)	Tempco Screen		4			13	nA	
-Iib(a)	Tempco Screen		4			16	nA	
-Iib(b)	Tempco Screen		4			10	nA	
-Iib(c)	Tempco Screen		4			13	nA	
PSRR	Tempco Screen		4			17	uV	

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.) AC: +Vcc = 30V, -Vcc = 0V

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
TR(tr)	Transient Response: Rise Time	+Vcc = 30V, -Vcc = Gnd				1	uS	7, 8A, 8B
TR(os)	Transient Response: Overshoot	+Vcc = 30V, -Vcc = Gnd				50	%	7, 8A, 8B
Sr+	Slew Rate: Rise	+Vcc = 30V, -Vcc = Gnd			0.1		V/uS	7, 8A, 8B
Sr-	Slew Rate: Fall	+Vcc = 30V, -Vcc = Gnd			0.1		V/uS	7, 8A, 8B
NI(BB)	Noise Broadband	+Vcc = 15V, -Vcc = -15V, BW = 10Hz to 5KHz	5			15	uV/rm	n 7
NI(PC)	Noise Popcorn	+Vcc = 15V, -Vcc = -15V, Rs = 20K Ohms	2			50	uV/pF	7
Cs	Channel Separation	+Vcc = 30V, -Vcc = Gnd	5		80		dB	7
	Separacion	+Vcc = 30V, -Vcc = Gnd, Vin = 1V and 16V, R1 = 2K Ohms	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, A to B	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, A to C	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, A to D	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, B to A	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, B to C	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, B to D	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, C to A	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, C to B	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, C to D	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, D to A	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, D to B	5		80		dB	7
		Rl = 2K Ohms, Vin = 1V and 16V, D to C	5		80		dB	7

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.) DC: "Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 only".

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Vio	Input Offset Voltage	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-1	1	mV	1
+Iib	Input Bias Current	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-15	15	nA	1
-Iib	Input Bias Current	Vcc+ = 30V, Vcc- = Gnd, Vcm = -15V			-15	15	nA	1

Note 1: V/mV = K.

Note 1: V/MV = K.

Note 2: Test on either A360, J273 AC or bench test.

Note 3: Calculated parameters.

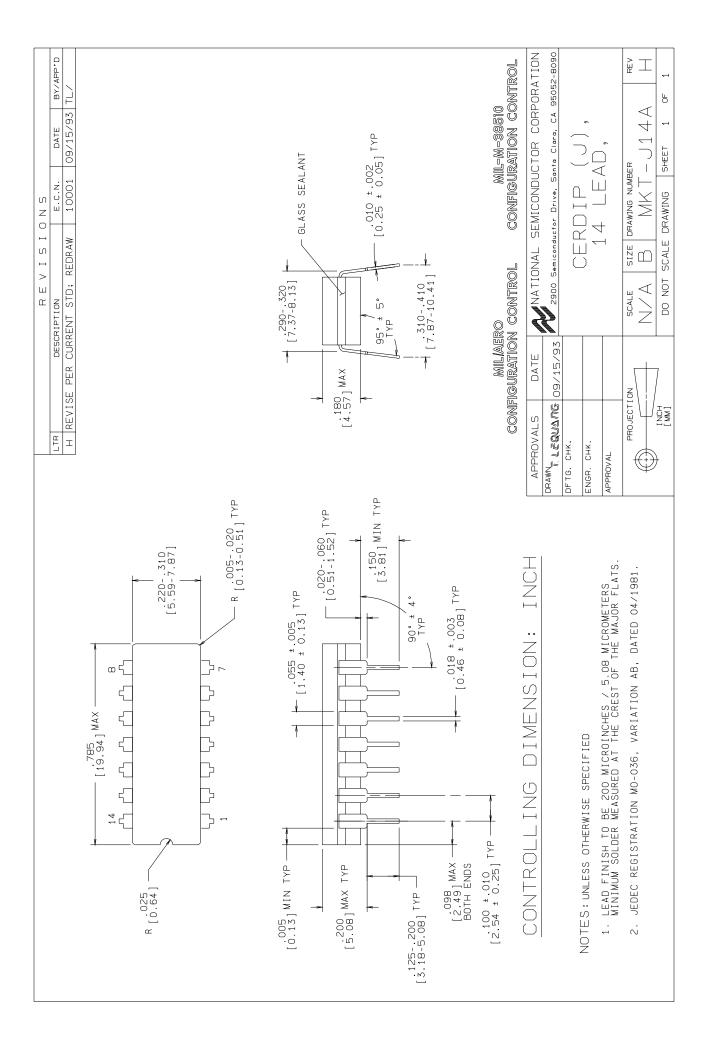
Note 4: Temp. Co. DLOG readings will print and MNET transfer will occur only in Test Mode 2 = 1. Bin 5 is a potential Temp. Co. failure.

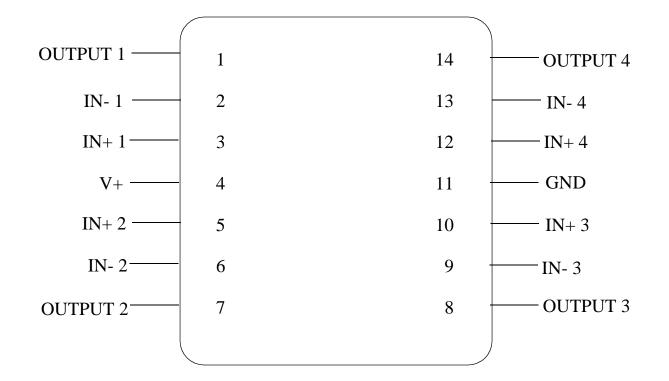
Note 5: Tested on LTX Channel Separation and Noise test tape.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05275HRA4	CERPACK (W), 14 LEAD (B/I CKT)
09173HRA2	CERDIP (J), 14 LEAD (B/I CKT)
J14ARH	CERDIP (J), 14 LEAD (P/P DWG)
P000254B	CERAMIC SOIC (WG), 14 LEAD (PINOUT)
P000288A	CERDIP (J), 14 LEAD (PINOUT)
P000474A	CERPACK (W), 14 LEAD (PIN OUT)
W14BRN	CERPACK (W), 14 LEAD (P/P DWG)
WG14ARC	CERAMIC SOIC (WG), 14LD (P/P DWG)

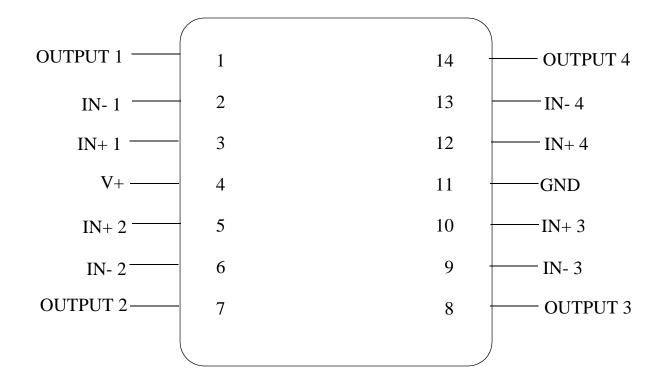
See attached graphics following this page.





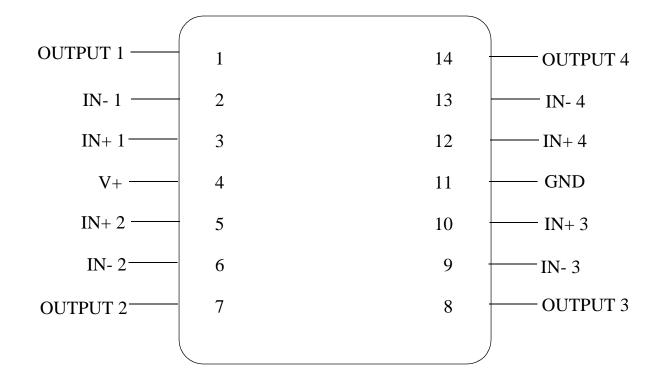
LM124AWG, LM124WG 14 - LEAD CERAMIC SOIC CONNECTION DIAGRAM TOP VIEW P000254B





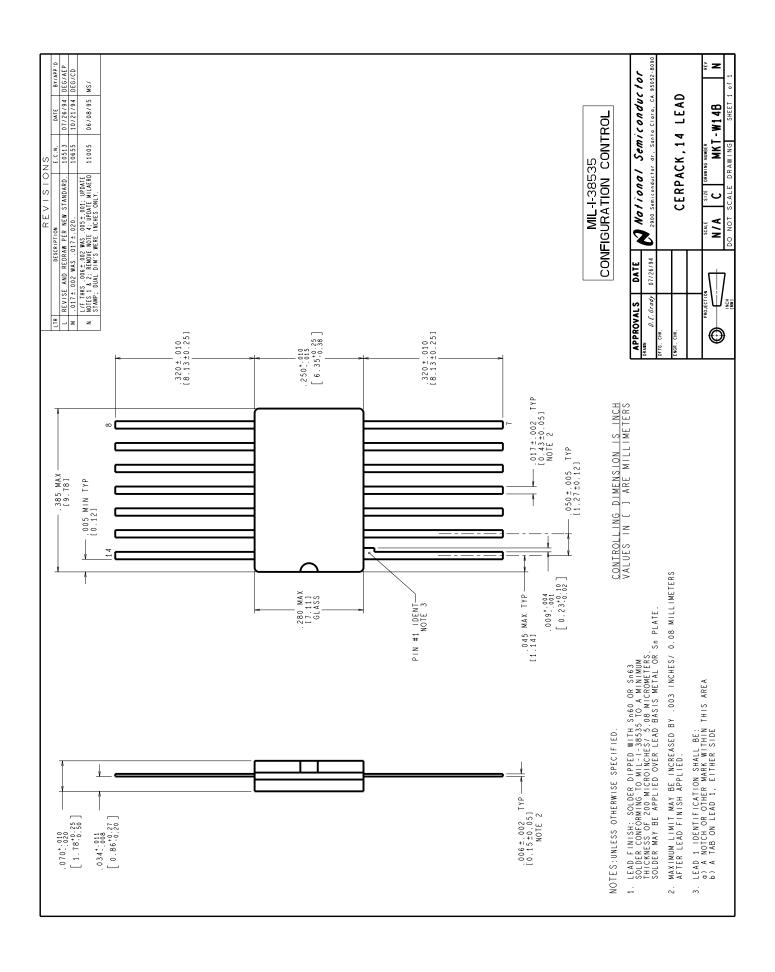
LM124AJ, LM124J 14 - LEAD DIP CONNECTION DIAGRAM TOP VIEW P000288A

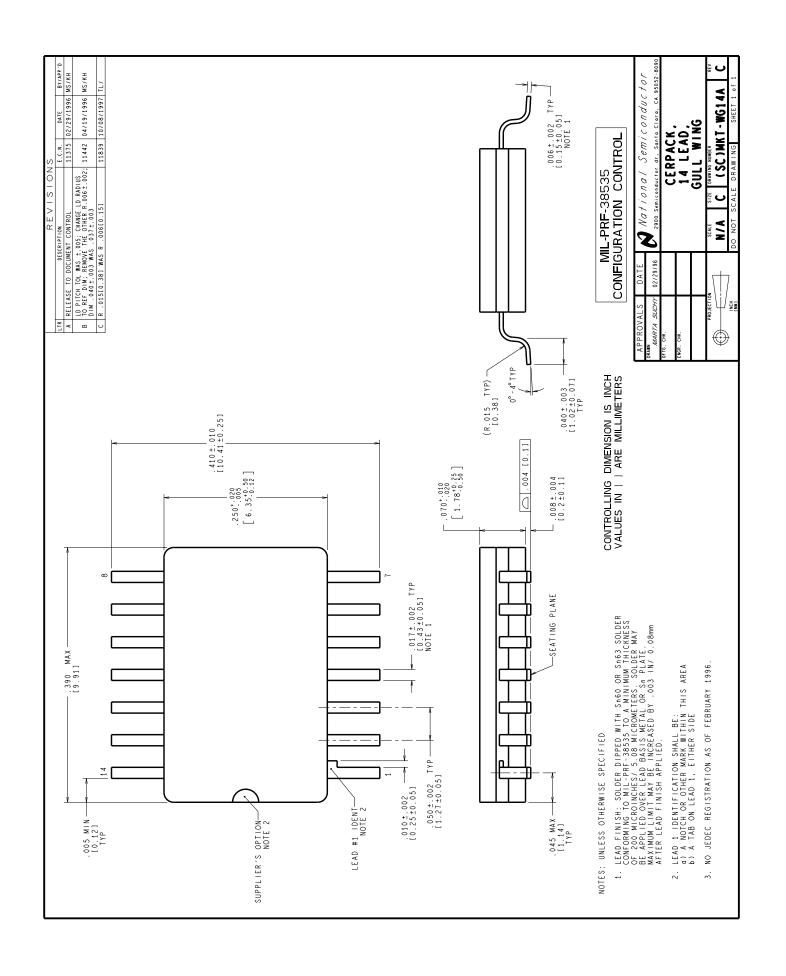




LM124AW, LM124W 14 - LEAD CERAMIC CERPACK CONNECTION DIAGRAM TOP VIEW P000474A







Revision History

Rev	ECN #	Rel Date	Originator	Changes
1A0	M0003654	03/28/02	Rose Malone	Update MDS - MJLM124-X, Rev. 0BL to Fully Released MDS, MJLM124-X, Rev. 1A0. Parameters Delta Vio/Delta T and Delta Iio/Delta T changed from +25 C \leq TA \leq +125 C and -55 C \leq TA \leq +25 C. Is Now, +25 C \leq TA \leq +125 C, +Vcc = 5V, -Vcc = 0V, Vcm = -1.4V and -55 C \leq TA \leq +25 C, +Vcc = 5V, -Vcc = 0V, Vcm = -1.4V. To clarify the Tempco test Conditions.
1B1	M0003979	03/28/02	Rose Malone	Update MDS: MJLM124-X, Rev. 1A0 to JMLM124-X, Rev. 1B1. Added WG pkg to Main Table, Absolute Maximum Ratings Section and Graphics Section.